NSN 5961-01-369-7618

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-369-7618 **Inclosure Material:** Metal and glass **Overall Length:** 0.250 inches **Terminal Length:** Between 0.115 inches and 0.135 inches **Overall Height:** 0.130 inches **Overall Width:** 0.060 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 breakdown voltage, dc **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius case **Special Features:** Dimensions include holder but not leads; junction pattern arrangement: pin **Precious Material And Location:** Holder plated gold **Precious Material:** Gold **Test Data Document:** 56232-1216947 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0